SCES428B - FEBRUARY 2003 - REVISED SEPTEMBER 2003

- Member of the Texas Instruments Widebus+™ Family
- Operates From 1.65 V to 3.6 V
- Inputs Accept Voltages to 5.5 V
- Max t_{pd} of 4.8 ns at 3.3 V
- Input and Output Ports Have Equivalent 26-Ω Series Resistors, So No External Resistors Are Required
- Typical V_{OLP} (Output Ground Bounce)
 <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 >2 V at V_{CC} = 3.3 V, T_A = 25°C

- I_{off} Supports Partial-Power-Down Mode Operation
- Supports Mixed-Mode Signal Operation on All Ports (5-V Input/Output Voltage With 3.3-V V_{CC})
- Other Products to Consider: SN74LVC32245, SN74LVCH32245A
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

description/ordering information

This 32-bit (quad-octal) noninverting bus transceiver is designed for 1.65-V to 3.6-V V_{CC} operation.

The SN74LVC32245A is designed for asynchronous communication between data buses. The control-function implementation minimizes external timing requirements.

This device can be used as four 8-bit transceivers, two 16-bit transceivers, or one 32-bit transceiver. It allows data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so that the buses are effectively isolated.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

The outputs, which are designed to sink up to 12 mA, include equivalent 26- Ω resistors to reduce overshoot and undershoot.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

ORDERING INFORMATION

TA	PACKAGE	t	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
-40°C to 85°C	LFBGA – GKE	Towns and and	SN74LVCR32245AGKER	NDO45A	
	LFBGA – ZKE (Pb-free)	Tape and reel	SN74LVCR32245AZKER	ND245A	

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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SN74LVCR32245A **32-BIT BUS TRANSCEIVER** WITH 3-STATE OUTPUTS SCES428B - FEBRUARY 2003 - REVISED SEPTEMBER 2003

GKE OR ZKE PACKAGE (TOP VIEW)

		1	2	3	4	5	6
Α	/	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
В		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
С		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
D		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
Е		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
F		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
G		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
н		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
J		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
K		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
L		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
M		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
N		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
Р		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
R		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
Т		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc
	1						

terminal assignments

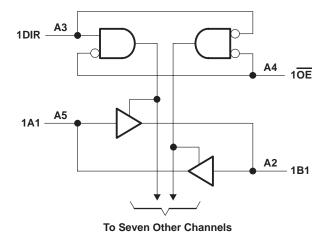
	1	2	3	4	5	6
Α	1B2	1B1	1DIR	1OE	1A1	1A2
В	1B4	1B3	GND	GND	1A3	1A4
С	1B6	1B5	Vcc	Vcc	1A5	1A6
D	1B8	1B7	GND	GND	1A7	1A8
Ε	2B2	2B1	GND	GND	2A1	2A2
F	2B4	2B3	Vcc	Vcc	2A3	2A4
G	2B6	2B5	GND	GND	2A5	2A6
Н	2B7	2B8	2DIR	2OE	2A8	2A7
J	3B2	3B1	3DIR	3OE	3A1	3A2
K	3B4	3B3	GND	GND	3A3	3A4
L	3B6	3B5	Vcc	Vcc	3A5	3A6
M	3B8	3B7	GND	GND	3A7	3A8
N	4B2	4B1	GND	GND	4A1	4A2
Р	4B4	4B3	Vcc	VCC	4A3	4A4
R	4B6	4B5	GND	GND	4A5	4A6
Т	4B7	4B8	4DIR	4OE	4A8	4A7

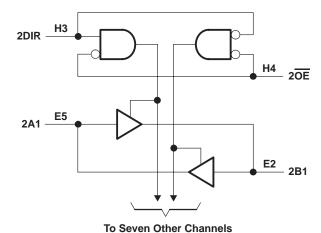
FUNCTION TABLE (each 8-bit section)

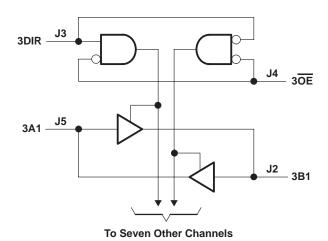
INP	UTS	ODED ATION
OE	DIR	OPERATION
L	L	B data to A bus
L	Н	A data to B bus
Н	X	Isolation

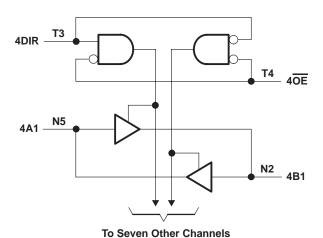


logic diagram (positive logic)









absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC}	
Voltage range applied to any output in the high-impedance or power-off state, V _O (see Note 1)	–0.5 V to 6.5 V
Voltage range applied to any output in the high or low state, V_{O}	
(see Notes 1 and 2)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I _{IK} (V _I < 0)	–50 mA
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Continuous output current, IO	±50 mA
Continuous current through each V _{CC} or GND	±100 mA
Package thermal impedance, θ, JA (see Note 3): GKE/ZKE package	
Storage temperature range, T _{stg}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
 - 2. The value of $V_{\hbox{\scriptsize CC}}$ is provided in the recommended operating conditions table.
 - 3. The package thermal impedance is calculated in accordance with JESD 51-7.



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recommended operating conditions (see Note 4)

			MIN	MAX	UNIT	
V	Complementaria	Operating	1.65	3.6	V	
VCC	Supply voltage	Data retention only	1.5		V	
		V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}			
V_{IH}	High-level input voltage	V _{CC} = 2.3 V to 2.7 V	1.7		V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2			
		V _{CC} = 1.65 V to 1.95 V		$0.35 \times V_{CC}$		
V_{IL}	Low-level input voltage	V _{CC} = 2.3 V to 2.7 V		0.7	V	
		V _{CC} = 2.7 V to 3.6 V		0.8	1	
٧ı	Input voltage		0	5.5	V	
.,		High or low state	0	VCC		
VO	Output voltage	3-state	0	5.5	V	
		V _{CC} = 1.65 V		-2		
		V _{CC} = 2.3 V		-4		
IOH	High-level output current	V _{CC} = 2.7 V		-8	mA	
		V _{CC} = 3 V		-12		
		V _{CC} = 1.65 V		2		
		V _{CC} = 2.3 V		4		
IOL	Low-level output current	V _{CC} = 2.7 V		8	mA	
		V _{CC} = 3 V		12		
Δt/Δν	Input transition rise or fall rate	•		10	ns/V	
TA	Operating free-air temperature		-40	85	°C	

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PA	RAMETER	TEST C	ONDITIONS	VCC	MIN	TYP [†]	MAX	UNIT		
		I _{OH} = -100 μA		1.65 V to 3.6 V	V _{CC} -0	.2				
		$I_{OH} = -2 \text{ mA}$		1.65 V	1.2					
.,		$I_{OH} = -4 \text{ mA}$		2.3 V	1.7			V		
VOH		1 0 m A		2.7 V	2			V		
		$I_{OH} = -8 \text{ mA}$		3 V	2.4					
		I _{OH} = -12 mA		3 V	2					
		I _{OL} = 100 μA		1.65 V to 3.6 V			0.2			
		I _{OL} = 2 mA		1.65 V			0.45			
VOL		I _{OL} = 4 mA		2.3 V			0.7	V		
		I _{OL} = 8 mA		2.7 V			0.6			
		I _{OL} = 12 mA		3 V			0.8			
II	Control inputs	V _I = 0 to 5.5 V		3.6 V			±5	μΑ		
l _{off}		V_I or $V_O = 5.5 V$		0			±10	μΑ		
loz‡		$V_0 = 0 \text{ to } 5.5 \text{ V}$		3.6 V			±5	μΑ		
		$V_I = V_{CC}$ or GND		0.01/			20	•		
ICC		$3.6 \text{ V} \le \text{V}_{\text{I}} \le 5.5 \text{ V}$	IO = 0	3.6 V	20		μΑ			
ΔICC		One input at V _{CC} – 0.6 V,	2.7 V to 3.6 V			500	μΑ			
Ci	Control inputs	$V_I = V_{CC}$ or GND		3.3 V		3		pF		
C _{io}	A or B ports	$V_O = V_{CC}$ or GND		3.3 V		12		pF		

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO (OUTPUT)	V _{CC} = ± 0.1		V _{CC} =		V _{CC} =	2.7 V	V _{CC} =	3.3 V 3 V	UNIT
	(INPUT) (OU	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A or B	B or A	1	7.8	1	5.8	1.5	5.7	1.5	4.8	ns
t _{en}	ŌĒ	A or B	1.5	10	1	8	1.5	7.9	1.5	6.3	ns
t _{dis}	ŌĒ	A or B	1.5	11.9	1	8.4	1.5	8.3	1.5	7.4	ns

operating characteristics, $T_A = 25^{\circ}C$

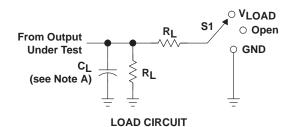
	PARAMETER	TEST CONDITIONS	V _{CC} = 1.8 V TYP	V _{CC} = 2.5 V TYP	V _{CC} = 3.3 V TYP	UNIT	
	.	Outputs enabled	(40.141)	35	38	43	
C _{pd}	Power dissipation capacitance	Outputs disabled f = 10 MHz		3	3	4	pF



[†] All typical values are at V_{CC} = 3.3 V, T_A = 25°C. ‡ For I/O ports, the parameter I_{OZ} includes the input leakage current.

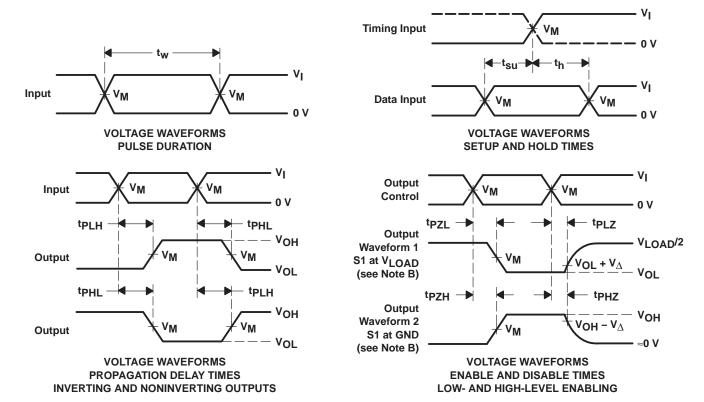
[§] This applies in the disabled state only.

PARAMETER MEASUREMENT INFORMATION



TEST	S1
tPLH/tPHL	Open
tPLZ/tPZL	VLOAD
tPHZ/tPZH	GND

.,	INF	PUTS	.,	.,	•	_	.,	
VCC	٧ _I	t _r /t _f	VM	VLOAD	CL	RL	V_Δ	
1.8 V ± 0.15 V	VCC	≤2 ns	V _{CC} /2	2×V _{CC}	30 pF	1 k Ω	0.15 V	
2.5 V \pm 0.2 V	VCC	≤2 ns	V _{CC} /2	2×V _{CC}	30 pF	500 Ω	0.15 V	
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V	
3.3 V \pm 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V	



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω .
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpLz and tpHz are the same as tdis.
 - F. tpz and tpzH are the same as ten.
 - G. tpLH and tpHL are the same as tpd.
 - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





PACKAGE OPTION ADDENDUM

27-Dec-2019

PACKAGING INFORMATION

Orderable Device	Status	Package Type	_	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN74LVCR32245AGKER	NRND	LFBGA	GKE	96	1000	TBD	SNPB	Level-2-235C-1 YEAR	-40 to 85	ND245A	
SN74LVCR32245AZKER	NRND	LFBGA	ZKE	96	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-260C-168 HR	-40 to 85	ND245A	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVCR32245AGKER	LFBGA	GKE	96	1000	330.0	24.4	5.7	13.7	2.0	8.0	24.0	Q1
SN74LVCR32245AZKER	LFBGA	ZKE	96	1000	330.0	24.4	5.7	13.7	2.0	8.0	24.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVCR32245AGKER	LFBGA	GKE	96	1000	336.6	336.6	41.3
SN74LVCR32245AZKER	LFBGA	ZKE	96	1000	336.6	336.6	41.3

GKE (R-PBGA-N96)

PLASTIC BALL GRID ARRAY



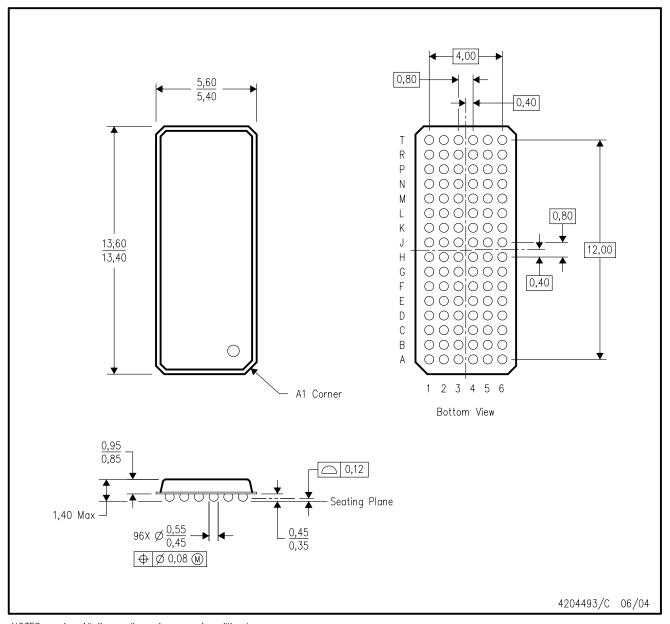
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-205 variation CC.
- D. This package is tin-lead (SnPb). Refer to the 96 ZKE package (drawing 4204493) for lead-free.



ZKE (R-PBGA-N96)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-205 variation CC.
- D. This package is lead-free. Refer to the 96 GKE package (drawing 4188953) for tin-lead (SnPb).



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